

Vishay Siliconix

Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET

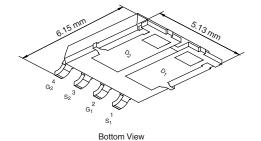
PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.014			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.015			
I _D (A) per leg	8			
Configuration	Dual			

FEATURES

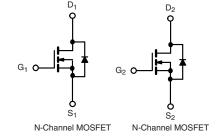
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R_a and UIS Tested
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 Qualified^d







PowerPAK® SO-8L Dual



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ912EP-T1-GE3

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	40	.,,	
Gate-Source Voltage	V _{GS}	± 20	V		
Continuous Drain Currenta	T _C = 25 °C	1	8	A	
Continuous Drain Current	T _C = 125 °C	I _D	8		
Continuous Source Current (Diode Conduction	on) ^a	I _S	8		
Pulsed Drain Current ^b		I _{DM}	32	l	
Single Pulse Avalanche Current		I _{AS}	33		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	56	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	Б	48	10/	
	T _C = 125 °C	P_{D}	16	W	
Operating Junction and Storage Temperature	e Range	T _J , T _{stg}	- 55 to + 175	۰.0	
Soldering Recommendations (Peak Temperature)e, f		-	260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	85	°C/W
Junction-to-Case (Drain)		R_{thJC}	3.1	C/VV

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.
- e. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SO-8L. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection..
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static	1			I.	·	·	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} =	= 0 V, I _D = 250 μA	40	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	1.3	1.8	2.3	V
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = 40 V	-		1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μΑ
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	150	1
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	30	-	-	Α
		V _{GS} = 10 V	I _D = 11 A	-	0.011	0.014	
Drain-Source On-State Resistance ^a	В	V _{GS} = 4.5 V	I _D = 8 A	-	0.012	0.015	Ω
	R _{DS(on)}	V _{GS} = 10 V	I _D = 11 A, T _J = 125 °C	-	-	0.021	
		V _{GS} = 10 V	I _D = 11 A, T _J = 175 °C	-	-	0.025	
Forward Transconductanceb	9 _{fs}	V _{DS}	= 15 V, I _D = 10 A	-	44	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	1799	2248	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 20 V, f = 1 MHz	-	282	352	pF
Reverse Transfer Capacitance	C _{rss}	1		-	109	136	1
Total Gate Charge ^c	Qg			-	31.5	48	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_D = 11.3 \text{ A}$	-	5.7	-	nC
Gate-Drain Charge ^c	Q _{gd}]		-	4.8	-	
Gate Resistance	R _g		f = 1 MHz	2.1	4.3	7	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	7	11	
Rise Time ^c	t _r	V _{DD} =	20 V, R_L = 1.77 Ω	-	21	32	
Turn-Off Delay Time ^c	t _{d(off)}	I _D ≅ 11.3 A	$V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	33	50	ns
Fall Time ^c	t _f			-	19	29	
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	=	32	Α
Forward Voltage	V _{SD}	I _F =	I _F = 8 A, V _{GS} = 0 V		0.8	1.1	V

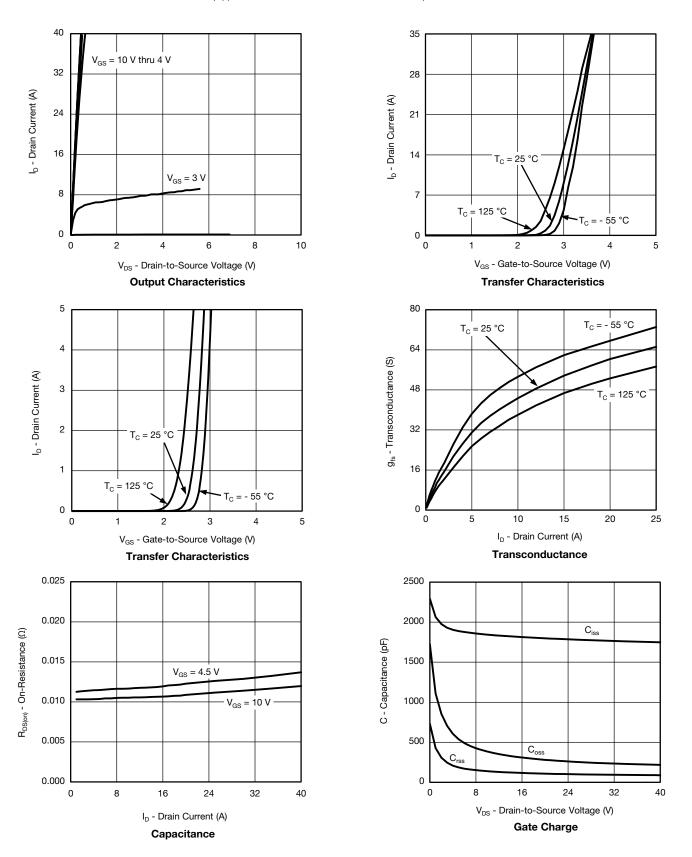
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

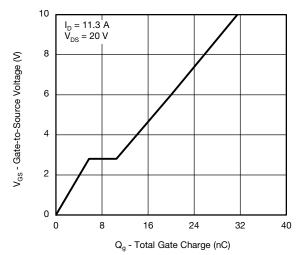


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

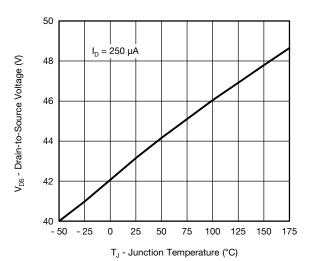




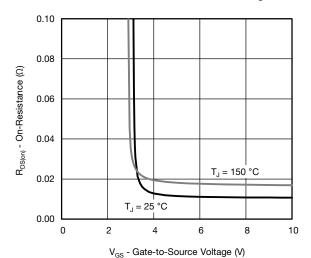
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



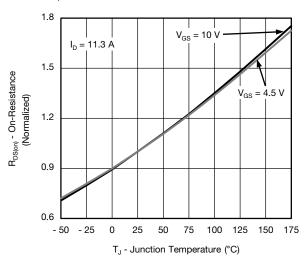
On-Resistance vs. Drain Current



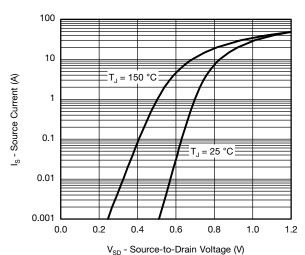
Source Drain Diode Forward Voltage



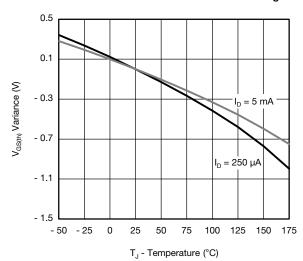
On-Resistance vs. Junction Temperature



Drain-Source Breakdown vs. Junction Temperature



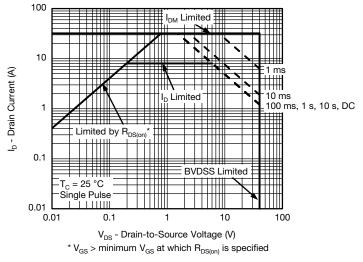
On-Resistance vs. Gate-to-Source Voltage



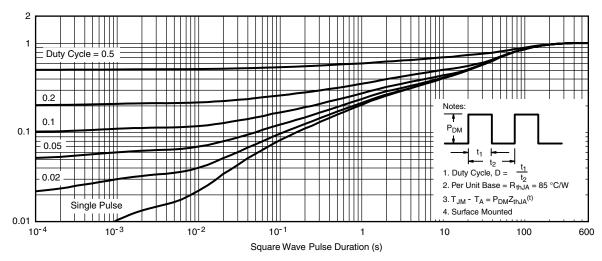


Normalized Effective Transient Thermal Impedance

THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



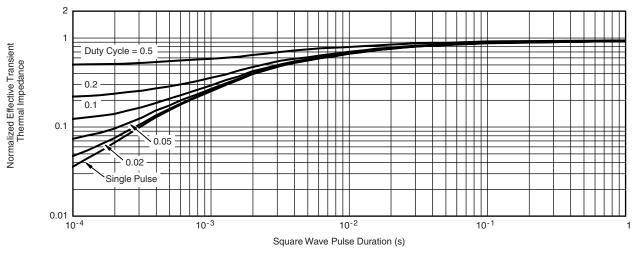
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

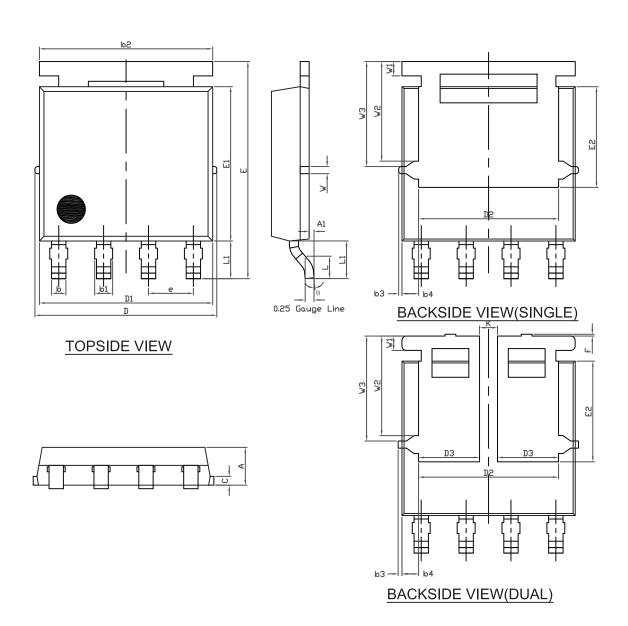
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg267330.

www.vishay.com

Vishay Siliconix

PowerPAK® SO-8L Case Outline



Package Information

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DIM.		MILLIMETERS			INCHES		
DIWI.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е	1.27 BSC			0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2 (for Al product)	2.75	2.85	2.95	0.108	0.112	0.116	
E2 (for other product)	3.18	3.28	3.38	0.125	0.129	0.133	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K	0.51			0.020			
W	0.23			0.009			
W1	0.41			0.016			
W2	2.82		0.111				
W3	2.96			0.117			
θ	0°	-	10°	0°	-	10°	

ECN: C12-0026-Rev. B, 27-Aug-12

DWG: 5976

Note

• Millimeters will gover



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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